



## 170 V power Schottky rectifier





#### **Features**

- · High junction temperature capability
- Low leakage current
- Good trade off between leakage current and forward voltage drop
- Low thermal resistance
- · High frequency operation
- Avalanche capability
- ECOPACK®2 compliant

### **Applications**

- · Switching diode
- SMPS
- DC/DC converter
- Telecom power

### **Description**

This dual diode common cathode Schottky rectifier is suited for high frequency switched mode power supplies.

Packaged in TO-247, the STPS61170C is optimized for use to enhance the reliability of the application.

| Product status                     |        |  |  |
|------------------------------------|--------|--|--|
| STPS61170C                         |        |  |  |
| Product summary                    |        |  |  |
| I <sub>F(AV)</sub> 2 x 30 A        |        |  |  |
| V <sub>RRM</sub>                   | 170 V  |  |  |
| <b>T</b> <sub>j(max.)</sub> 175 °C |        |  |  |
| V <sub>F(typ.)</sub>               | 0.63 V |  |  |



#### 1 Characteristics

Table 1. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

| Symbol              | Parameter  | Value                      | Unit       |      |    |
|---------------------|--|----------------------------|------------|------|----|
| $V_{RRM}$           | Repetitive peak reverse voltage  |                            |            | 170  | V  |
| I <sub>F(RMS)</sub> | Forward rms current  |                            |            | 80   | Α  |
|                     | A  | T <sub>c</sub> = 150 °C    | Per diode  | 30   |    |
| I <sub>F(AV)</sub>  | Average forward current, $\delta$ = 0.5, square wave                     | T <sub>c</sub> = 145 °C    | Per device | 60   | Α  |
| I <sub>FSM</sub>    | Surge non repetitive forward current                                     | t <sub>p</sub> = 10 ms sin | 500        | Α    |    |
| P <sub>ARM</sub>    | Repetitive peak avalanche power $t_p = 10 \mu s$ , $T_j = 125 ^{\circ}C$ |                            |            |      | W  |
| T <sub>stg</sub>    | Storage temperature range  | -65 to +175                | °C         |      |    |
| Tj                  | Maximum operating junction temperature (1)                               |                            |            | +175 | °C |

<sup>1.</sup>  $(dP_{tot}/dT_i) < (1/R_{th(i-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameters

| Symbol                                | Parameter        |           | Typ. value | Unit |  |
|---------------------------------------|------------------|-----------|------------|------|--|
| R <sub>th(i-c)</sub> Junction to case |                  | Per diode | 0.9        | °C/W |  |
| $R_{th(j-c)}$                         | Junction to case | Total     | 0.6        | C/VV |  |
| R <sub>th(c)</sub>                    | Coupling         |           | 0.3        | °C/W |  |

When the diodes 1 and 2 are used simultaneously:  $\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} \times R_{\text{th(j-c)}}$  (per diode) +  $P_{\text{(diode2)}} \times R_{\text{th(c)}}$ 

For more information, please refer to the following application note:

• AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics (per diode)

| Symbol                        | Parameter                     | Test conditions         |                       | Min. | Тур. | Max. | Unit |
|-------------------------------|-------------------------------|-------------------------|-----------------------|------|------|------|------|
| I <sub>R</sub> <sup>(1)</sup> | Davis and Landra and American | T <sub>j</sub> = 25 °C  | $V_R = V_{RRM}$       | -    |      | 60   | μA   |
| IR (7                         | Reverse leakage current       | T <sub>j</sub> = 125 °C |                       | -    | 16   | 60   | mA   |
|                               |                               | T <sub>j</sub> = 25 °C  | I <sub>F</sub> = 30 A | -    |      | 0.84 | V    |
| V <sub>F</sub> <sup>(2)</sup> | Convert voltage drep          | T <sub>j</sub> = 125 °C |                       | -    | 0.63 | 0.67 |      |
| VF (=)                        |                               | T <sub>j</sub> = 25 °C  | I <sub>F</sub> = 60 A | -    |      | 0.92 |      |
|                               |                               | T <sub>j</sub> = 125 °C |                       | -    | 0.76 | 0.80 |      |

- 1. Pulse test:  $t_p = 5$  ms,  $\delta < 2\%$
- 2. Pulse test:  $t_p$  =380  $\mu$ s,  $\delta$  < 2%

To evaluate the conduction losses, use the following equation:  $P = 0.54 \times I_{F(AV)} + 0.0043 \times I_{F}^{2}$  (RMS)

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

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### 1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current (per diode)

P<sub>F(AV)</sub>(W)

δ=0.05 δ=0.1 δ=0.2 δ=0.5

δ=1.0

Figure 2. Average forward current versus ambient temperature ( $\delta = 0.5$ , per diode)  $I_{F(AV)}(A)$  $R_{th(j-a)}=R_{th(j-c)}$ 

Figure 3. Normalized avalanche power derating versus pulse duration (T<sub>i</sub>= 125 °C)

 $I_{F(AV)}(A)$ 

δ=tp/T

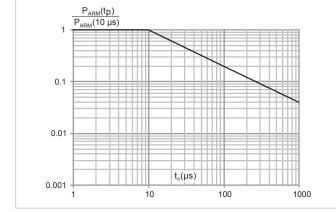
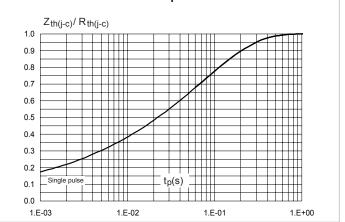


Figure 4. Relative variation of thermal impedance junction to case versus pulse duration



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Figure 5. Reverse leakage current versus reverse voltage applied (typical values, per diode)

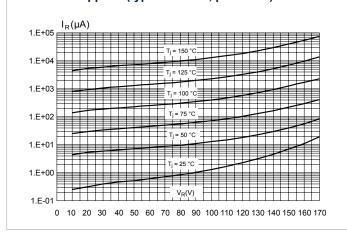


Figure 6. Junction capacitance versus reverse voltage applied (typical values, per diode)

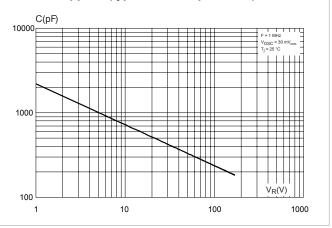


Figure 7. Forward voltage drop versus forward current (per diode, low level)

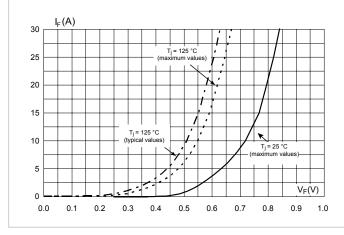
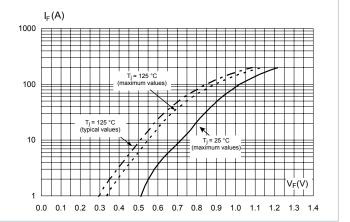


Figure 8. Forward voltage drop versus forward current (per diode, high level)



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## Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

### 2.1 TO-247 package\_information

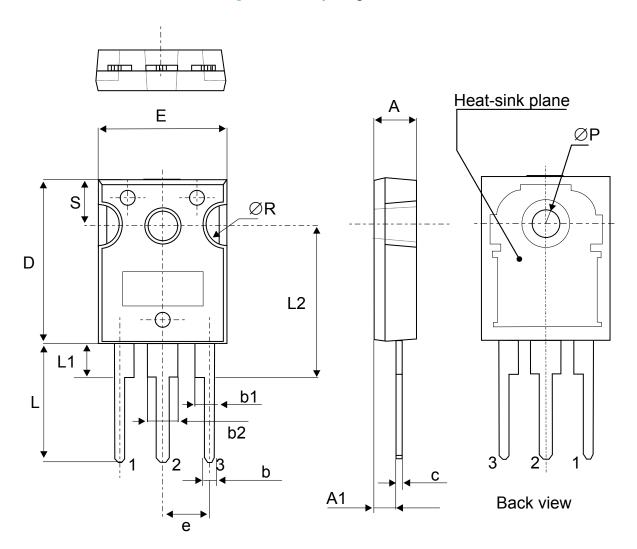
• Epoxy meets UL94, V0

Cooling method: by conduction (C)

Recommended torque value: 0.8 N·m

Maximum torque value: 1.0 N·m

Figure 9. TO-247 package outline



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Table 4. TO-247 package mechanical data

|      |       |             | Dime  | nsions |       |       |
|------|-------|-------------|-------|--------|-------|-------|
| Ref. |       | Millimeters |       | only)  |       |       |
| Ī    | Min.  | Тур.        | Max.  | Min.   | Тур.  | Max.  |
| Α    | 4.85  |             | 5.15  | 0.191  |       | 0.203 |
| A1   | 2.20  |             | 2.60  | 0.086  |       | 0.102 |
| b    | 1.00  |             | 1.40  | 0.039  |       | 0.055 |
| b1   | 2.00  |             | 2.40  | 0.078  |       | 0.094 |
| b2   | 3.00  |             | 3.40  | 0.118  |       | 0.133 |
| С    | 0.40  |             | 0.80  | 0.015  |       | 0.031 |
| D    | 19.85 |             | 20.15 | 0.781  |       | 0.793 |
| Е    | 15.45 |             | 15.75 | 0.608  |       | 0.620 |
| е    | 5.30  | 5.45        | 5.60  | 0.209  | 0.215 | 0.220 |
| L    | 14.20 |             | 14.80 | 0.559  |       | 0.582 |
| L1   | 3.70  |             | 4.30  | 0.145  |       | 0.169 |
| L2   |       | 18.50       |       |        | 0.728 |       |
| ØP   | 3.55  |             | 3.65  | 0.139  |       | 0.143 |
| ØR   | 4.50  |             | 5.50  | 0.177  |       | 0.217 |
| S    | 5.30  | 5.50        | 5.70  | 0.209  | 0.216 | 0.224 |

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# 3 Ordering information

Table 5. Order code

| Order code  | Marking     | Package | Weight | Base qty. | Delivery mode |
|-------------|-------------|---------|--------|-----------|---------------|
| STPS61170CW | STPS61170CW | TO-247  | 4.36 g | 30        | Tube          |

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## **Revision history**

Table 6. Document revision history

| Date        | Revision | Changes   |
|-------------|----------|---|
| 16-Sep-2005 | 1        | First issue.  |
| 01-Dec-2010 | 2        | Updated Table 2 and added Figure 11.  |
| 27-Jul-2018 | 3        | Updated Table 1. Absolute ratings (limiting values per diode at 25 $^{\circ}$ C, unless otherwise specified) and Figure 3. Normalized avalanche power derating versus pulse duration ( $T_j$ = 125 $^{\circ}$ C). |

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